Luminescence enhancement in Eu$^{3+}$-doped $\alpha$- and $\gamma$-Al$_2$O$_3$ produced by pressure-assisted low-temperature combustion synthesis

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Intense red luminescence in Eu$^{3+}$-doped gamma ($\gamma$) and alpha ($\alpha$) alumina (Al$_2$O$_3$) phosphors obtained by direct and indirect combustion synthesis at low-temperatures is reported. $\gamma$ and $\alpha$-(Al$_{1-x}$Eu$_x$)$_2$O$_3$ are easily produced by combustion synthesis at 280 °C in the range of $x = 0.001$–0.06 at. %. The well-defined direct synthesis allows europium ions to incorporate into the $\alpha$ or $\gamma$ alumina lattice in spite of the large size difference between these ions and the aluminum cations in Al$_2$O$_3$. These materials yield a strong fluorescence at room temperature due to $f$–$f$ transition lines within Eu$^{3+}$ (4$^2$F$^0$) electron emission configuration. Furthermore, from luminescence measurements, it is deduced that Eu$^{3+}$ occupy low-symmetry sites in the Al$_2$O$_3$ lattice. © 2004 American Institute of Physics. [DOI: 10.1063/1.1650908]

The optical properties of rare-earth (RE) ions in different host materials have been extensively studied for several years. Although there are several reports on this subject, in recent years, considerable attention has been focused on submicrometer/nanometer-sized particles doped with RE ions, since it has been shown that a reduction in particle size often results in an improvement of their structural, electronic, and optical properties.

The interest in RE-doped nanocrystals is fueled by their potential in the fabrication of optical devices, such as optical amplifiers, display phosphors in optoelectronic applications, and microlasers in a submicron dimension. This requires that the RE-based nanoparticles be synthesized and integrated with functional substrates, such as single crystals, ceramic microspheres, and nanofibers. It was demonstrated that such materials, especially the ceramics built from nanocrystals, are characterized by pronounced optical properties.

Among the materials investigated to date, few studies have been performed on RE ion-doped aluminum oxide (Al$_2$O$_3$). Several structural modifications of Al$_2$O$_3$ are known with $\alpha$-Al$_2$O$_3$, the only stable phase. $\alpha$-Al$_2$O$_3$ is a material with a significant technological importance because of the large optical transparency from an ultraviolet to near-infrared wavelength, excellent mechanical properties, and good chemical stability. Similarly, among the variety of RE ions commonly used to dope different kinds of materials, europium ions (Eu$^{3+}$) have attracted significant attention because they have tremendous potential for applications as phosphors, electroluminescent devices, optical amplifiers or lasers, and high density optical storage.

The emission spectrum of Eu$^{3+}$ shows emission lines extending from visible to the near infrared with a relatively simple energy level structure, especially the $^5D_0 \rightarrow 7F_J$ ($J = 1, 2, 3, \ldots$) manifold which enables one to ascertain the microscopic symmetry around the site, making it an ideal experimental probe of the crystalline environment.

In this work, $\alpha$- and $\gamma$-(Al$_{1-x}$Eu$_x$)$_2$O$_3$ powders were synthesized using two preparation methods: A direct and an indirect combustion synthesis. In the direct method, combustion synthesis was carried out at atmospheric pressure. In contrast, in the indirect route, the combustion synthesis was carried out in the presence of an additional pressure in the reactor. The reaction is exothermic and occurred at $\sim 280$ °C. Several structural modifications of Al$_2$O$_3$ are known with $\alpha$-Al$_2$O$_3$, the only stable phase. $\alpha$-Al$_2$O$_3$ is a material with a significant technological importance because of the large optical transparency from an ultraviolet to near-infrared wavelength, excellent mechanical properties, and good chemical stability. Similarly, among the variety of RE ions commonly used to dope different kinds of materials, europium ions (Eu$^{3+}$) have attracted significant attention because they have tremendous potential for applications as phosphors, electroluminescent devices, optical amplifiers or lasers, and high density optical storage.

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Until recently, this RE-doped $\alpha$-Al$_2$O$_3$ materials have only been synthesized by sol–gel techniques, ion-beam implantation, and sonochemical preparation. In the indirect route, the combustion synthesis was carried out in the presence of an additional pressure in the reactor. A flux of 80 sccm of argon was added. The vessel containing the mixture was introduced into the reactor. The reaction is exothermic and occurred at $\sim 280$ °C (self-ignition temperature). A $\gamma$-(Al$_{1-x}$Eu$_x$)$_2$O$_3$ ($x = 0.001$–0.06 at. %) powders were prepared using europium nitrate (Eu(NO$_3$)$_3$·6H$_2$O), aluminum nitrate (Al(NO$_3$)$_3$·9H$_2$O), and hydrazine $(N_2H_4·H_2O)$ as a reductive noncarbonaceous fuel that prevents carbon contamination. As soon as the nitrates were dissolved in deionized water, the hydrazine was added. The vessel containing the mixture was introduced into the reactor. A flux of 80 sccm of argon (Ar) was established for 15 min in order to create an inert atmosphere. At this time, the heating process was initiated and the temperature was monitored via a thermocouple system. From this point, two process conditions were used. In the direct process, the Ar pressure was not allowed to build up in the reaction chamber. The chamber was continuously vented with Ar flux.
Contrarily, in the indirect process, after the first 15 min of Ar flux, the exhaust valve was closed allowing Ar to pressurize the reactor chamber to 0.2 MPa in order to let the reaction take place in this pressurized environment. The pressure inside the reactor was ~1.3 MPa just when the reaction started and by the time the reaction was completed (about 1 s), the pressure reached ~5 MPa due to the reaction gases.

The phase development in the as-synthesized product and the temperature dependence on the structure formation of the two methods of synthesis, x-ray diffraction (XRD) measurements were carried out using a $\theta$–2$\theta$ diffractometer excited with Cu $K\alpha$ radiation.

The XRD patterns for the powders of (Al$_{1-x}$Eu$_{x}$)$_2$O$_3$ ($x=0$, 0.005, and 0.015 at.%) obtained through the direct process are shown in Fig. 1. From Fig. 1(a), it is clear that through this method, without pressurizing the reactor, it is possible to directly synthesize ~100% of $\alpha$-Al$_2$O$_3$. The vigorous nature of the reaction is capable of accelerating the kinetics and, therefore, forming $\alpha$-Al$_2$O$_3$ without the need for high-temperature treatments, which drastically increase the crystallite size. From Figs. 1(b) and 1(c), it is evident that the combustion synthesis process allows the incorporation of Eu into the $\alpha$-Al$_2$O$_3$ lattice despite the large size difference between Eu$^{3+}$ ($\sim$0.9 Å) and the Al$^{3+}$ ($\sim$0.5 Å). It is also observed that the presence of the europium ions in the Al$_2$O$_3$ network inhibits the formation of the $\alpha$ phase in the as-synthesized state. The prevention of the $\alpha$-phase formation is more accentuated when the concentration of the dopant ions is increased.

Figure 2 shows the XRD patterns for the powders of (Al$_{0.995}$Eu$_{0.005}$)$_2$O$_3$ obtained through indirect synthesis (as synthesized and heat treated for 2 h in air at: 1200°C, 1300°C, and 1700°C). Figure 2 helps to elucidate the phase development during heat treatment of the doped powders. It shows that heat treating $\gamma$-(Al$_{1-x}$Eu$_{x}$)$_2$O$_3$ forms $\theta$-(Al$_{1-x}$Eu$_{x}$)$_2$O$_3$, then $\alpha$-(Al$_{1-x}$Eu$_{x}$)$_2$O$_3$, and ultimately a mixture of $\alpha$-(Al$_{1-x}$Eu$_{x}$)$_2$O$_3$ and AlEuO$_3$, which implies the crystallization of another phase. It is also observed that the presence of the europium ions retards the formation of the $\alpha$-phase to temperatures above 1200°C. In general, this transformation occurs below 1200°C for undoped Al$_2$O$_3$.

The luminescence properties were investigated by measuring the photoluminescence (PL) spectra of the annealed powders. The PL spectra were recorded using a monochromator (Spex/Triax-180) and detected by a charge coupled device (CCD) camera. The light from a 450 W xenon lamp through the monochromator (Spex/Triax-180) was used for the optical excitation. Figure 3 shows the PL emission spectra, performed at room temperature, of (Al$_{1-x}$Eu$_{x}$)$_2$O$_3$ for $x=0.003$–0.040 samples prepared by the direct method and annealed at 1200°C for 2 h. The PL spectra of these powders, excited at a wavelength of 395 nm, correspond to the $6^{5}F_{0}\rightarrow6^{7}I_{6}$ transition in a direct excitation of the luminescence center. All samples yield intense red emissions around 614 nm. The red emission can be assigned to the hypersensitive $5^{2}D_{0}\rightarrow5^{7}F_{2}$ transition using a forced electric dipole transition mechanism, which is a parity forbidden $f$–$f$ transition. The peak emission at 594 nm is due to the $5^{2}D_{0}\rightarrow5^{7}F_{1}$ magnetic dipole transition and is structurally independent. It can be observed that the samples containing 1.5 and 4.0 at. % of europium show inhomogeneous broad peaks characteristic of Eu$^{3+}$ ions occupying a variety of vacant sites in the $\theta$-Al$_2$O$_3$ phase. In contrast, the 0.3 at. % sample presents the narrow peaks corresponding to $5^{2}D_{0}\rightarrow5^{7}F_{J}$, $J=1$, 2, 4 transitions, $J=4$ being the most intense emission. This behavior arise from the fact that, at 0.3 at. % of Eu concentration, there are not enough dopant ions to prevent the formation of the $\alpha$-Al$_2$O$_3$ at 1200°C.
The cathodoluminescence (CL) emission spectra of the samples were collected using a monochromator (Spectra/Triax-180) through an optical fiber and detected by a CCD camera. Figure 4 shows the CL spectra, excited with a 5 keV electron beam of (Al0.965Eu0.035)2O3 annealed at different temperatures. The spectra consists of a series of well resolved features at 598, 614, and 690 nm, which are assigned to $^5D_0 \rightarrow ^7F_j$, $J=1, 2, 4$, transitions, respectively. These emission lines can reveal much about the local environment of the Eu$^{3+}$ ion. Among the $^5D_0 \rightarrow ^7F_j$ transitions, the selection rules make the $^5D_0 \rightarrow ^7F_1$ and $^5D_0 \rightarrow ^7F_2$ transitions of particular interest. The emission band at 598 nm, which corresponds to the $^5D_0 \rightarrow ^7F_1$ transition, is a magnetic dipole transition and hardly varies with the crystal field strength around Eu$^{3+}$. However, the hypersensitive transition $^5D_0 \rightarrow ^7F_2$ at 614 nm is electric dipole allowed, consequently, it depends on the local electric field and, hence, the local symmetry. From these considerations, it is clear that the $(^5D_0 \rightarrow ^7F_2)/(^5D_0 \rightarrow ^7F_j)$ intensity ratio, called the asymmetry ratio, gives a measure of the degree of distortion from the inversion symmetry of the local environment of the Eu$^{3+}$ ion lattice. The asymmetry ratio of the (Al$_{1-x}$Eu$_x$)$_2$O$_3$ sample heat treated at 1300 °C is calculated as 4.0 and for the sample treated at 1400 °C has a value of 3.6. A large value of the asymmetry ratio obtained for both samples are indicative of strong electric fields of low symmetry at the Eu$^{3+}$ ions. Both results suggest that Eu$^{3+}$ ions occupy low symmetry sites as theoretically inferred by Verdozzi et al.$^{12}$ It is clear that the asymmetry ratio decreases with an increase of the thermal treatment. For the sample annealed at 1700 °C, the asymmetry ratio is dramatically reduced, to about 1.7, suggesting that the $^5D_0 \rightarrow ^7F_2$ transition is now strongly forbidden due to a change in the symmetry occupied by most of the Eu$^{3+}$ ions. We also observe an increase in the $^5D_0 \rightarrow ^7F_4$ transition at this temperature of annealing. Depicted in the inset of Fig. 4 is a plot of the CL emission spectra of (Al$_{0.965}$Eu$_{0.035}$)$_2$O$_3$ samples obtained through the two preparation methods and heat treated in air for 2 h at 1300 °C. When compared the CL intensity of the $^5D_0 \rightarrow ^7F_2$ transition, at 614 nm, the sample prepared by the direct method offers the best performance for CL applications. We believe that the best CL performance offered by the samples obtained through the direct method is due to the formation of larger crystals of α-Al$_2$O$_3$. It is also observed that, independent of the synthesis route, all samples presented an asymmetry ratio of 4.0, which indicates that the Eu$^{3+}$ ions occupy a site with no inversion symmetry.

In summary, it is shown that two polycrystalline phases of Eu$^{3+}$-doped alumina, γ-Al$_2$O$_3$ or α-Al$_2$O$_3$ for $x=0.001$–0.06 can be obtained by pressure-assisted low-temperature combustion synthesis. With these methods, it is possible to obtain highly luminescent Eu$^{3+}$-doped Al$_2$O$_3$ powders at temperatures of ~280 °C, that present uniformity and small particle sizes. The initial pressure is the crucial parameter in the controlled synthesis of Eu$^{3+}$-doped γ-Al$_2$O$_3$ or α-Al$_2$O$_3$ polycrystalline phases. The direct (Al$_{1-x}$Eu$_x$)$_2$O$_3$ synthesis is an advantageous way, concerning the temperature the submicrocrystalline formation and the product morphology, which may be the reason for the high CL intensity achieved by this method. Additionally, this well-defined synthesis condition allows europium ions to incorporate easily into the (α or γ)-Al$_2$O$_3$ lattices in spite of the large size difference between Eu and Al ionic radii. Strong PL in nanocrystalline γ-Al$_2$O$_3$:Eu$^{3+}$ excited at λ=395 nm and high intensity CL in α-Al$_2$O$_3$:Eu$^{3+}$ phosphors were measured at room temperature due to $f$–$f$ transition lines within Eu$^{3+}$ (4f$^6$) electron emission configuration. Furthermore, from the analysis of the luminescence spectra which are revealed by the local environment of the Eu$^{3+}$, it is established that europium ions occupy low symmetry sites in the network structure. These are important criteria for the application of these phosphors in lamps and displays.

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